

1.5V Drive Nch MOSFET

RW1C015UN

●Structure

Silicon N-channel MOSFET

●Features

- 1) Low On-resistance.
 - 2) High power package.
- Low voltage drive. (1.5V)

●Applications

Switching

●Packaging specifications

Type	Package	Taping
	Code	T2R
	Basic ordering unit (pieces)	8000
RW1C015UN		○

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DSS}	20	V	
Gate-source voltage	V_{GSS}	± 10	V	
Drain current	Continuous	I_D	± 1.5	A
	Pulsed	I_{DP} *1	± 3	A
Source current (Body diode)	Continuous	I_S	0.5	A
	Pulsed	I_{SP} *1	3	A
Total power dissipation	P_D *2	0.7	W	
Channel temperature	T_{ch}	150	°C	
Range of Storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

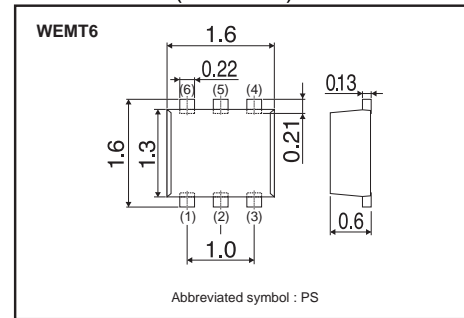
*2 When mounted on a ceramic board

●Thermal resistance

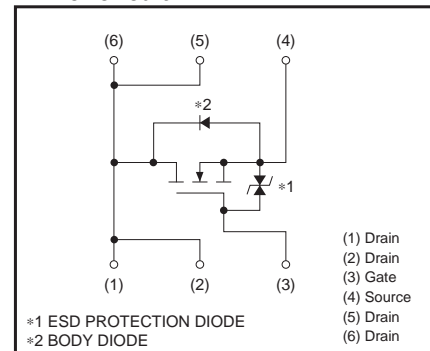
Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$ *	179	°C / W

* When mounted on a ceramic board

●Dimensions (Unit : mm)



●Inner circuit



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	–	–	±10	μA	V _{GS} = ±10V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR) DSS}	20	–	–	V	I _D = 1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	–	–	1	μA	V _{DS} = 20V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	0.3	–	1.0	V	V _{DS} = 10V, I _D = 1mA
Static drain-source on-state resistance	R _{DS (on)} *	–	130	180	mΩ	I _D = 1.5A, V _{GS} = 4.5V
		–	170	240	mΩ	I _D = 1.5A, V _{GS} = 2.5V
		–	220	310	mΩ	I _D = 0.8A, V _{GS} = 1.8V
		–	300	600	mΩ	I _D = 0.3A, V _{GS} = 1.5V
Forward transfer admittance	Y _{fs} *	1.6	–	–	S	V _{DS} = 10V, I _D = 1.5A
Input capacitance	C _{iss}	–	110	–	pF	V _{DS} = 10V
Output capacitance	C _{oss}	–	18	–	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	–	15	–	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	–	5	–	ns	V _{DD} ≐ 10V
Rise time	t _r *	–	5	–	ns	I _D = 1A V _{GS} = 4.5V
Turn-off delay time	t _{d (off)} *	–	20	–	ns	R _L ≐ 10Ω
Fall time	t _f *	–	3	–	ns	R _G =10Ω
Total gate charge	Q _g *	–	1.8	–	nC	V _{DD} ≐ 10V I _D = 1.5A
Gate-source charge	Q _{gs} *	–	0.3	–	nC	V _{GS} = 4.5V
Gate-drain charge	Q _{gd} *	–	0.3	–	nC	R _L ≐ 6.7Ω R _G =10Ω

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	–	–	1.2	V	I _S = 1.5A, V _{GS} =0V

*Pulsed

●Electrical characteristics curves

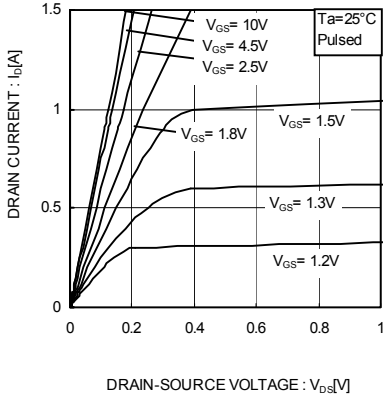


Fig.1 Typical Output Characteristics(I)

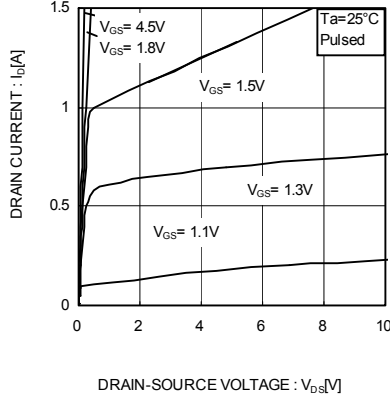


Fig.2 Typical Output Characteristics(II)

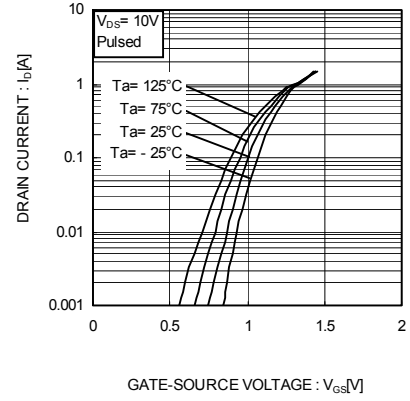


Fig.3 Typical Transfer Characteristics

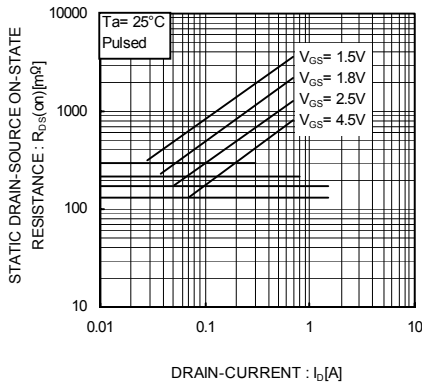


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

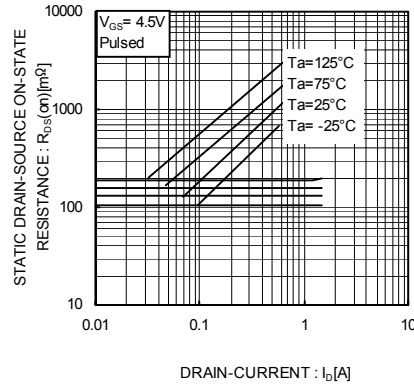


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

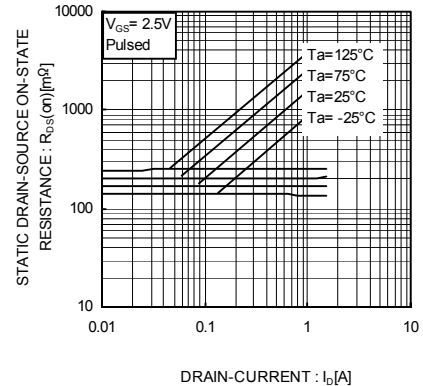


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

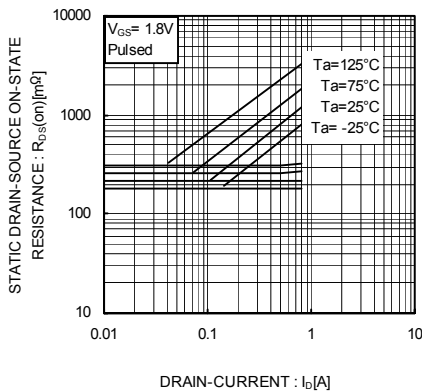


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

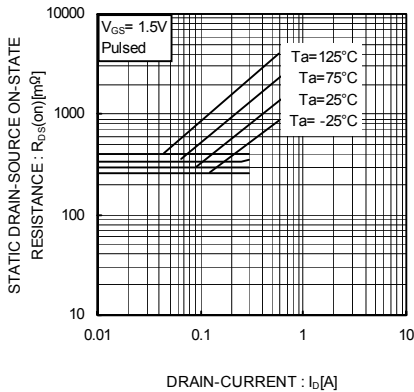


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(V)

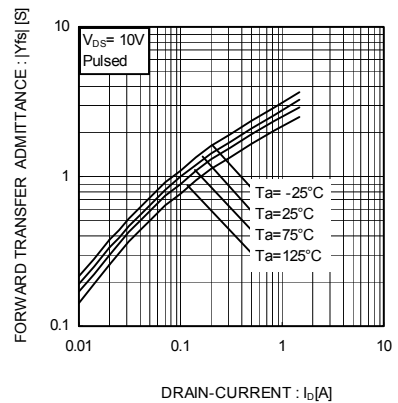


Fig.9 Forward Transfer Admittance vs. Drain Current

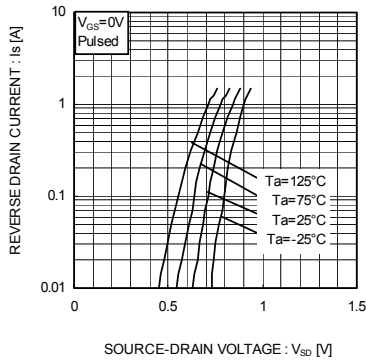


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

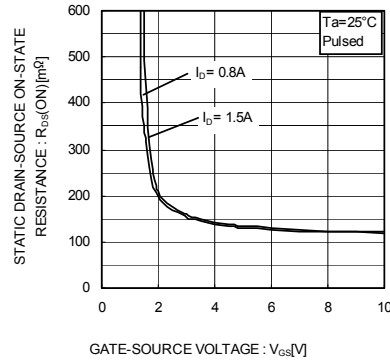


Fig.11 Static Drain-Source On-State Resistance vs. Gate Source Voltage

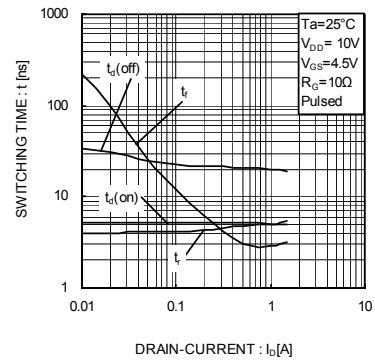


Fig.12 Switching Characteristics

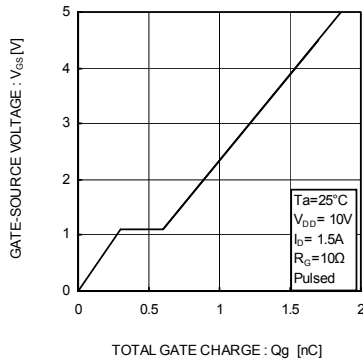


Fig.13 Dynamic Input Characteristics

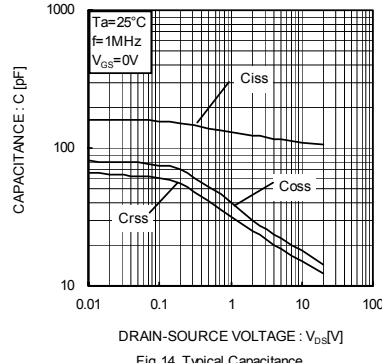


Fig.14 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuit

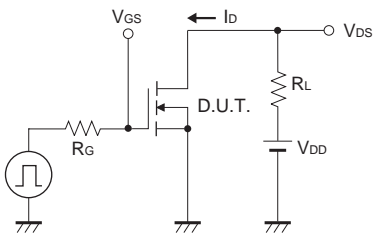


Fig.1-1 Switching Time Measurement Circuit

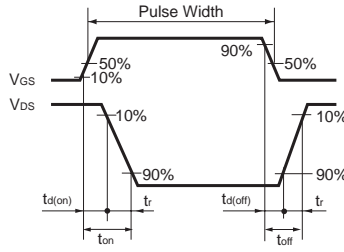


Fig.1-2 Switching Waveforms

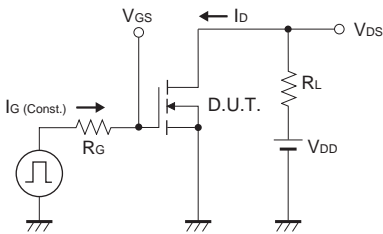


Fig.2-1 Gate Charge Measurement Circuit

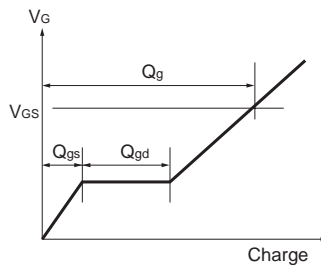


Fig.2-2 Gate Charge Waveform

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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